**WHAT IS CLAIMED IS:**

1. A wafer processing method of processing a wafer in which each of devices having a plurality of bumps is formed in each of regions of a front surface partitioned by a plurality of division lines formed in an intersecting manner, the wafer processing method comprising:

a cut groove forming step of forming cut grooves each having a depth corresponding to a finished thickness of each of device chips by a cutting blade along the division lines from a front surface side of the wafer;

a sealing step of sealing the front surface of the wafer including the cut grooves with a sealing material, after the cut groove forming step is performed;

a grinding step of grinding the wafer from a back surface side of the wafer to the finished thickness of each of the device chips to expose the sealing material in the cut grooves, after the sealing step is performed;

an alignment step of detecting an alignment mark through the sealing material by visible light imaging means from the front surface side of the wafer, and detecting the division line to be laser processed based on the alignment mark without removing the sealing material at the peripheral portion of the front surface

of the wafer, after the grinding step is performed; and

a dividing step of emitting a laser beam of such a wavelength as to be absorbed in the sealing material along the division lines from the front surface side of the wafer, and dividing the wafer by ablation processing into individual device chips each of which has its front surface and four side surfaces surrounded by the sealing material, after the alignment step is performed; and

the alignment step is performed while obliquely irradiating a region to be captured by the visible light imaging means with light by oblique light means,

wherein in the alignment step, the vertical illumination of the visible light imaging means and the light from the oblique light means are applied to a region to be captured by the visible light imaging means.

2. The wafer processing method according to claim 1, wherein, the sealing member contains carbon black; and

the content of the carbon black is 0.1% by mass or more and 0.2% by mass or less.